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INFORMATION DISCLOSURE STATEMENT BY APPLICANT

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Sheet 1 of 1

Complete if Known

Application Number 09/161,981
 Confirmation Number 8269
 Filing Date September 29, 1998
 First Named Inventor Akitaka KIMURA
 Art Unit 2812
 Examiner Name J. Davie
 Attorney Docket Number Q51885

U.S. PATENT DOCUMENTS

Examiner Initials*	Cite No. ¹	Document Number		Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document
		Number	Kind Code ² (if known)		
		US			
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FOREIGN PATENT DOCUMENTS

Examiner Initials*	Cite No. ¹	Foreign Patent Document			Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Translation
		Country Code ³	Number ⁴	Kind Code ⁵ (if known)			
San		JP	H08-18159		01-19-1996		No
San		JP	H04-340284		11-26-1992		No
San		JP	H09-036473		02-07-1997		No
San		JP	H08-264454		10-11-1996		No
San		JP	H09-036475		02-07-1997		No
San		JP	H09-199791		07-31-1997		No

OTHER ART - NON PATENT LITERATURE DOCUMENTS

Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city, and/or country where published.	Translation
San		Nakamura et al., Ridge-geometry InGa _N multi-quantum-well-structure laser diodes, Appl. Phys. Lett., 69(1996) 1577.	
San		S. Nakamura et al., Bluish-Pruple InGa _N Multi-Quantum Well Structure Laser Diodes, Extended Abstracts of 1996 International Conference on Solid State Devices and Materials, Yokohama, 1996, pp.67-69	
		Isamu Akasaki III-V-Family Compound Semiconductors: Baifukan, 1994, page 335	

Examiner Signature

Date Considered

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